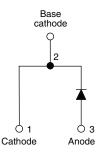
VS-HFA25PB60-N3

Vishay Semiconductors

HEXFRED[®] Ultrafast Soft Recovery Diode, 25 A



www.vishay.com



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
I _{F(AV)}	25 A					
V _R	600 V					
V _F at I _F	1.3 V					
t _{rr} (yp.	23 ns					
T _J max.	150 °C					
Package	TO-247AC 2L, TO-247AC 3L					
Circuit configuration	Single					

FEATURES

- Ultrafast and ultrasoft recovery
- Very low I_{RRM} and Q_{rr}
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization for definitions of FREE compliance please see www.vishay.com/doc?99912

BENEFITS

- Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION

VS-HFA25PB60... is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 25 A continuous current, the VS-HFA25PB60... is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{BBM}) and does not exhibit any tendency to "snap-off" during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA25PB60 ... is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

MECHANICAL DATA

Case: TO-247AC 2L, TO-247AC 3L

Molding compound meets UL 94 V-0 flammability rating **Terminal:** matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Cathode to anode voltage	V _R		600	V
Maximum continuous forward current	١ _F	T _C = 100 °C	25	
Single pulse forward current	I _{FSM}	t _p = 10 ms	225	А
Maximum repetitive forward current	I _{FRM}		100	
Maximum power dissipation	PD	T _C = 25 °C	151	W
Maximum power dissipation		T _C = 100 °C	60	vv
Operating junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C

Revision: 14-Oct-2022

1

Document Number: 94064

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RoHS

COMPLIANT

VS-HFA25PB60-N3



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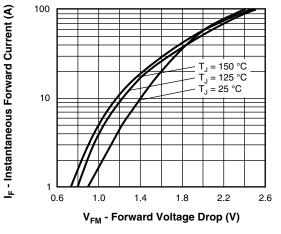
ELECTRICAL SPECIFICATIONS (T_J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS	
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA		600	-	-		
	I _F = 25 A		I _F = 25 A	See fig. 1	-	1.3	1.7	V
Maximum forward voltage	V _{FM}	I _F = 50 A	-		1.5	2.0		
		I _F = 25 A, T _J = 125 °C	-		1.3	1.7		
Maximum reverse		$V_{R} = V_{R}$ rated	See fig. 2	-	1.5	20	μA	
leakage current	IRM	$T_J = 125 \text{ °C}, V_R = 0.8 \text{ x } V_R \text{ rated}$	See lig. 2	-	600	2000	μΑ	
Junction capacitance	CT	V _R = 200 V	See fig. 3	-	55	100	pF	
Series inductance	Ls	Measured lead to lead 5 mm from p	ackage body	-	12	-	nH	

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS	
	t _{rr}	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 $	A/μs, V _R = 30 V	-	23	-		
Reverse recovery time See fig. 5, 10	t _{rr1}	T _J = 25 °C		-	50	75	ns	
See lig. 5, 10	t _{rr2}	T _J = 125 °C		-	105	160		
Peak recovery current	recovery current I _{RRM1} T _J = 25 °C		-	4.5	10	А		
See fig. 6, 10	I _{RRM2}	T _J = 125 °C	I _F = 25 A	-	8.0	15	A	
Reverse recovery charge	Q _{rr1}	T _J = 25 °C	dI _F /dt = 200 A/µs	-	112	375	nC	
See fig. 7, 10	Q _{rr2}	T _J = 125 °C	V _R = 200 V	-	420	1200	nc	
Peak rate of fall of recovery	dl _{(rec)M} /dt1	T _J = 25 °C]	-	250	-		
current during t _b See fig. 8, 10	dl _{(rec)M} /dt2	T _J = 125 °C		-	160	-	A/µs	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C	
Thermal resistance, junction to case	R _{thJC}		-	-	0.83		
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	40	K/W	
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	0.25	-		
Weight			-	6.0	-	g	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf ·cm (lbf ·in)	
Marking device		Case style TO-247AC 2L, TO-247AC 3L		HFA2	5PB60	•	



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Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current

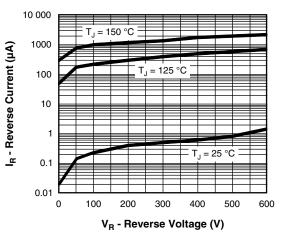


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

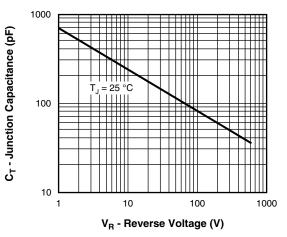


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

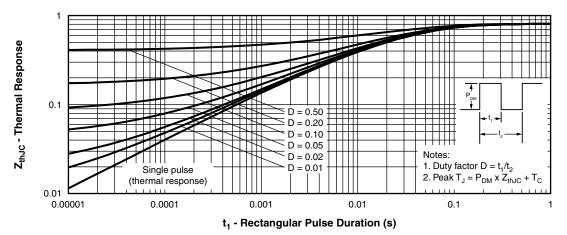


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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140

120

t_{rr} (ns)

$\begin{array}{c} 1400\\ I_{F} = 50 \text{ A} \\ I_{F} = 25 \text{ A} \\ I_{F} = 10 \text{ A} \\ 1000 \end{array}$

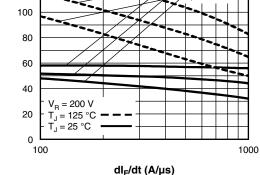


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt

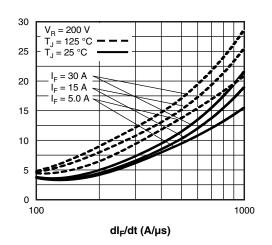
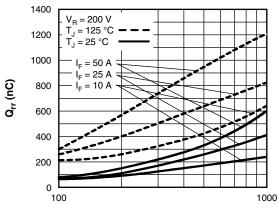


Fig. 6 - Typical Recovery Current vs. dl_F/dt







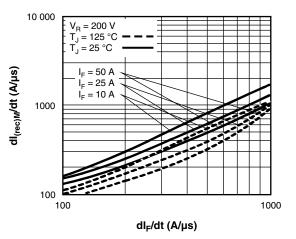


Fig. 8 - Typical $dI_{(rec)M}/dt$ vs. dI_F/dt

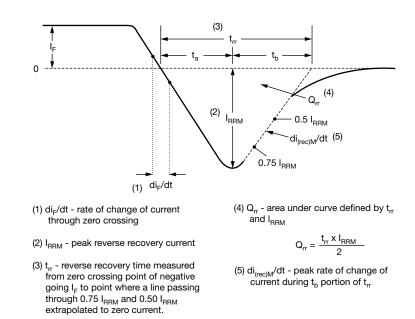


Fig. 9 - Reverse Recovery Waveform and Definitions

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I_{RR} (A)

VS-HFA25PB60-N3

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ORDERING INFORMATION TABLE

Device code	VS-	HF	Α	25	РВ	60	-N3
		2	3	4	5	6	(7)
	 Vishay Semiconductors product HEXFRED[®] family 						
	3 - Electron irradiated						
	4 - Current rating (25 = 25 A)						
	5 -	PB	= TO-24	47AC, 2	pins		

6 Voltage rating: (60 = 600 V) -

7 Environmental digit:

-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-HFA25PB60-N3	25	500	Antistatic plastic tube			

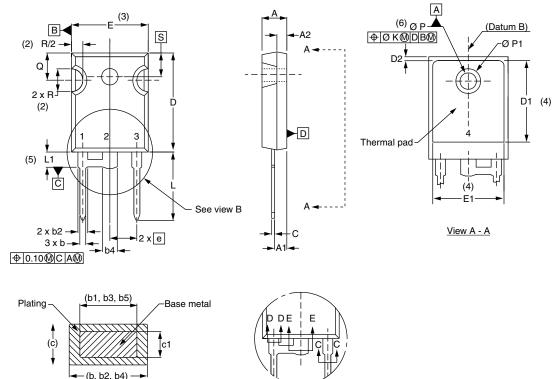
LINKS TO RELATED DOCUMENTS					
Dimonsiona	TO-247AC 2L	www.vishay.com/doc?96144			
Dimensions	TO-247AC 3L	www.vishay.com/doc?96138			
Part marking information	TO-247AC 2L	www.vishay.com/doc?95648			
Fart marking information	TO-247AC 3L	www.vishay.com/doc?95007			



Vishay Semiconductors

TO-247AC modified - 50 mils L/F

DIMENSIONS in millimeters and inches



Section C - C, D - D, E - E

(4)

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View B

SYMPOL	SYMBOL MILLIMETERS INCHES		NOTES		
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.17	1.37	0.046	0.054	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
с	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STINDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.35	0.020	0.053	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46 BSC		0.215	BSC	
ØК	0.254		0.010		
L	14.20	16.10	0.559	0.634	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	7.39	-	0.291	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51	BSC	0.217 BSC		

Notes

- ⁽¹⁾ Dimensioning and tolerance per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- ⁽⁴⁾ Thermal pad contour optional with dimensions D1 and E1
- ⁽⁵⁾ Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension c and Q

Revision: 20-Apr-17

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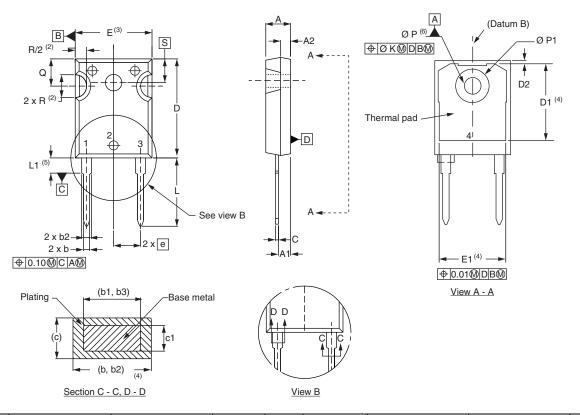
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TO-247AC 2L

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NULES
A	4.65	5.31	0.183	0.209		E	15.29	15.87	0.602	0.625	3
A1	2.21	2.59	0.087	0.102		E1	13.46	-	0.53	-	
A2	1.17	1.37	0.046	0.054		e	5.46 BSC		0.215 BSC		
b	0.99	1.40	0.039	0.055		ØК	0.254		0.010		
b1	0.99	1.35	0.039	0.053		L	14.20	16.10	0.559	0.634	
b2	1.65	2.39	0.065	0.094		L1	3.71	4.29	0.146	0.169	
b3	1.65	2.34	0.065	0.092		ØР	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035		Ø P1	-	7.39	-	0.291	
c1	0.38	0.84	0.015	0.033		Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3	R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4	S	5.51 BSC		0.217 BSC		
D2	0.51	1.35	0.020	0.053							
NI - I											

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁴⁾ Thermal pad contour optional with dimensions D1 and E1

⁽⁵⁾ Lead finish uncontrolled in L1

(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension Q

Revision: 07-Dec-17

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